

**TECHNICAL DATA,  
DATA SHEET 5053 REV. A**

**HERMETIC SILICON CARBIDE RECTIFIER**

**DESCRIPTION:** A 1200-VOLT, 10 AMP POWER SILICON CARBIDE RECTIFIER IN A CERAMIC HERMETIC LCC-3P PACKAGE

**FEATURES:**

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR
- SCREENED VERSIONS ARE AVAILABLE

**MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_C = 25^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	1200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C = 65^\circ\text{C}$ )	$I_O$	10	Amps
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C = 65^\circ\text{C}$ , for Single Package)	$I_O$	5	Amps
MAXIMUM REPETITIVE FORWARD SURGE CURRENT PER LEG ( $t = 8.3\text{ms}$ , Sine) $T_C = 25^\circ\text{C}$	$I_{FRM}$	30	Amps
MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG ( $t = 10\mu\text{s}$ , pulse) $T_C = 25^\circ\text{C}$	$I_{FSM}$	100	Amps
MAXIMUM POWER DISSIPATION, $T_C = 25^\circ\text{C}$	$P_d$	15	W
MAXIMUM THERMAL RESISTANCE, Junction to Case (per dual package)	$R_{\theta JC}$	1.30	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE*	Top & Tstg	-55 to +200	$^\circ\text{C}$

\* Note: SiC semiconductors will handle at or above this operating and storage temperature. However, extended operational use of the packaged device above 175C may reduce its future performance. All qualification testing and screening per MIL-PRF-19500 will only be performed to 175C.

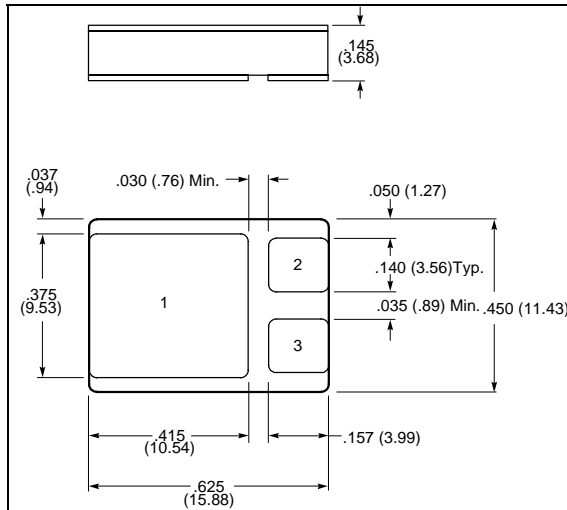
**ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	TYP	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP ( $I_f = 5\text{ A}$ per leg) $V_f$	$T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$	1.6 2.6	1.8 3.0 Volts
MAXIMUM REVERSE CURRENT (1200V PIV per leg) $I_r$	$T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$	0.05 0.10	0.20 1.00 mA
TOTAL CAPACITIVE CHARGE ( $V_R = 1200\text{V}$ $I_F = 5\text{A}$ $di/dt = 500\text{A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$ ) $Q_C$ per leg		28	N/A nC
MAXIMUM JUNCTION CAPACITANCE ( $V_f = 5\text{V}$ ) PER LEG	$C_T$	450	PF

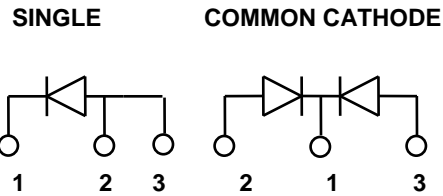
Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited. Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.

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**MECHANICAL DIMENSIONS: IN Inches / mm**



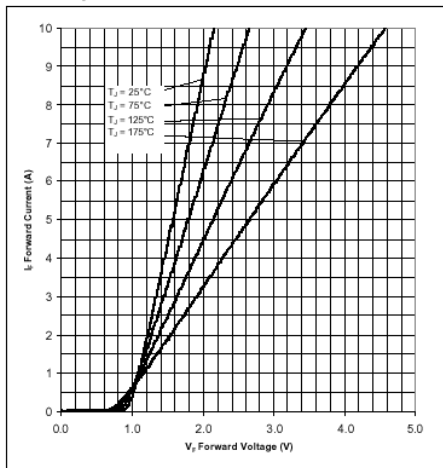
**LCC-3P**



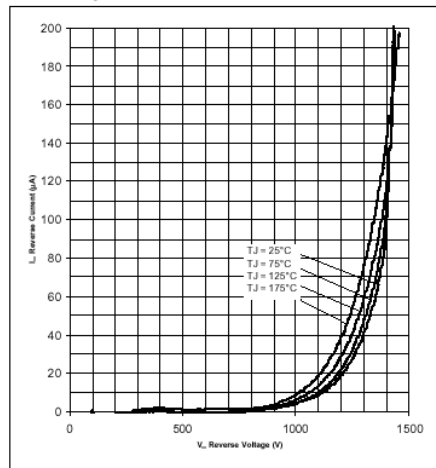
**NOU TABLE**

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SHD619052 SINGLE RECTIFIER	CATHODE	ANODE	ANODE
SHD619052P COMMON CATHODE	COMMON CATHODE	ANODE 1	ANODE 2

**Figure 1. Forward Characteristics**



**Figure 2. Reverse Characteristics**



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